

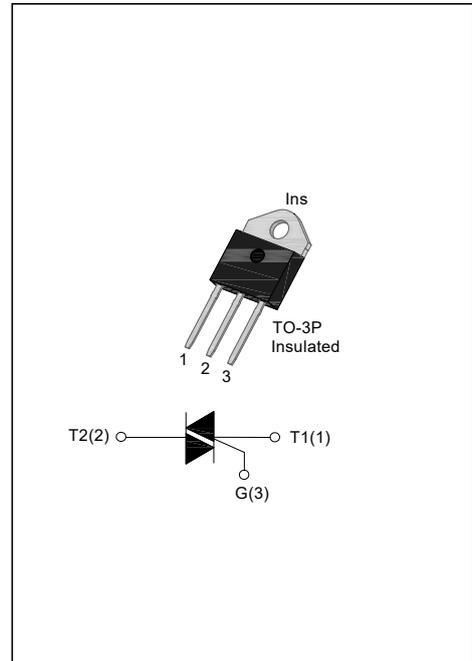


DESCRIPTION:

JST60Z Series triacs provide good commutation capability, which is suitable for general purpose AC switching and voltage regulation, and can be used in static relays, heating regulation, induction motor starting circuits. JST60Z triac provides an insulation voltage of 2500 V_{RMS}, complying with UL standards (File ref: E252906). Package TO-3P is RoHS compliant. (2011/65/EU)

MAIN FEATURES

Symbol	Value	Unit
V _{DRM} /V _{R_{RRM}}	1200/1600	V
I _{T(RMS)}	60	A
I _{GT1-3}	≤50	mA



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T _{stg}	-40-150	°C
Operating junction temperature range	T _j	-40-125	°C
Repetitive peak off-state voltage (T _j =25°C)	V _{DRM}	1200/1600	V
Repetitive peak reverse voltage (T _j =25°C)	V _{R_{RRM}}	1200/1600	V
RMS on-state current TO-3P(Ins) (T _C =70°C)	I _{T(RMS)}	60	A
Non repetitive surge peak on-state current (t _p =20ms)	I _{TSM}	600	A
I ² t value for fusing (t _p =10ms)	I ² t	1800	A ² s
Critical rate of rise of on-state current (I _G = 2 × I _{GT})	dI/dt	100	A/μs
Peak gate current	I _{GM}	8	A
Average gate power dissipation	P _{G(AV)}	2	W
Peak gate power	P _{GM}	10	W
Peak pulse voltage (T _j =25°C; non-repetitive, off-state; FIG.7)	V _{PP}	1.1	kV

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant		Value	Unit
I_{GT}	$V_D=12\text{V } R_L=33\Omega$	I - II -III	MAX	50	mA
V_{GT}		I - II -III	MAX	1.3	V
V_{GD}	$V_D=V_{DRM} T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$	I - II -III	MIN	0.2	V
I_L	$I_G=1.2I_{GT}$	I - II -III	MAX	120	mA
I_H	$I_T=100\text{mA}$		MAX	80	mA
dv/dt	$V_D=2/3V_{DRM} T_j=125^\circ\text{C}$ Gate Open		MIN	1500	V/ μs

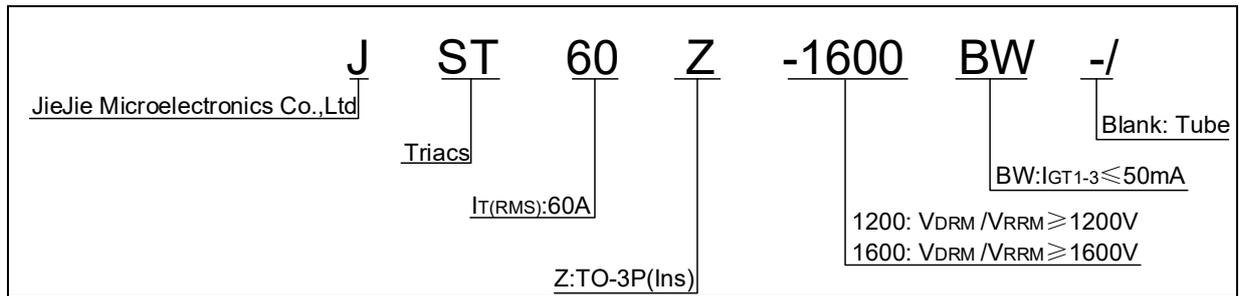
STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX)	Unit
V_{TM}	$I_{TM}=85\text{A } t_p=380\mu\text{s}$	$T_j=25^\circ\text{C}$	1.7	V
V_{TO}	Threshold voltage	$T_j=125^\circ\text{C}$	0.85	V
R_D	Dynamic resistance	$T_j=125^\circ\text{C}$	9.2	m Ω
I_{DRM}	$V_D=V_{DRM} V_R=V_{RRM}$	$T_j=25^\circ\text{C}$	20	μA
I_{RRM}		$T_j=125^\circ\text{C}$	8	mA

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	junction to case(AC)	TO-3P(Ins)	0.62	$^\circ\text{C/W}$

ORDERING INFORMATION



MARKING

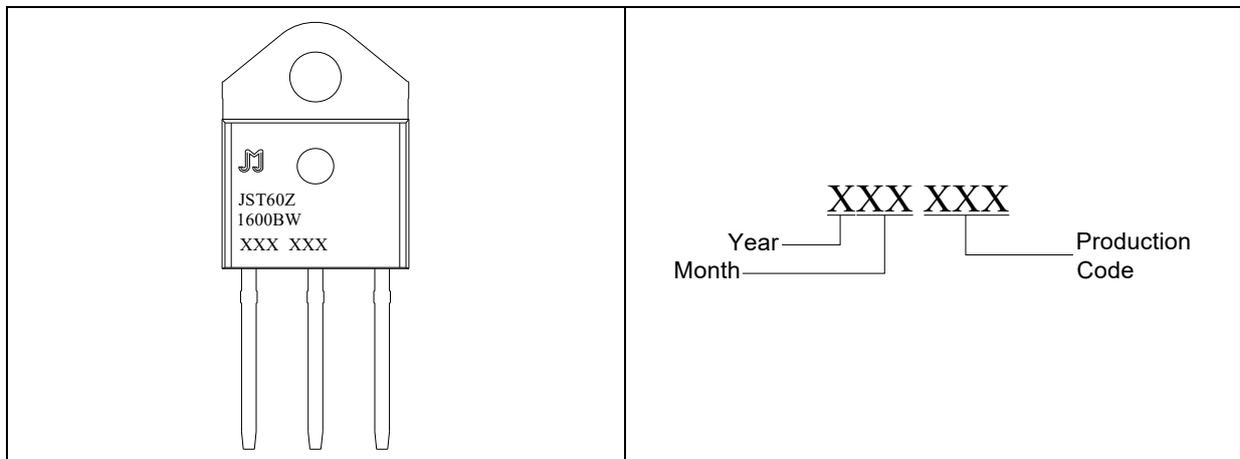


FIG.1: Maximum power dissipation versus RMS on-state current

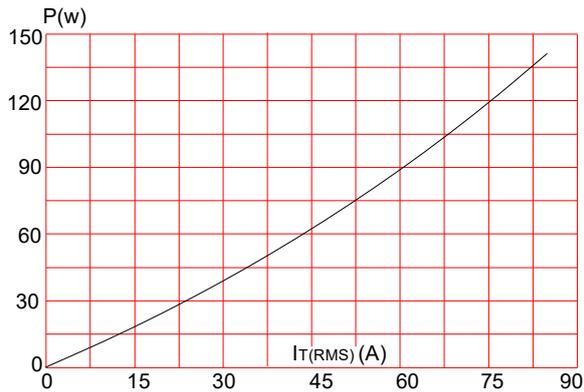


FIG.2: RMS on-state current versus case temperature

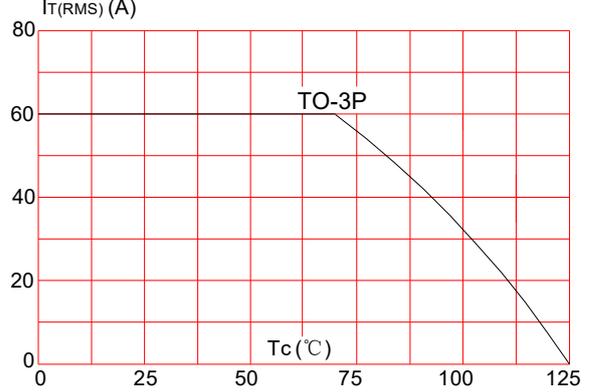


FIG.3: Surge peak on-state current versus number of cycles

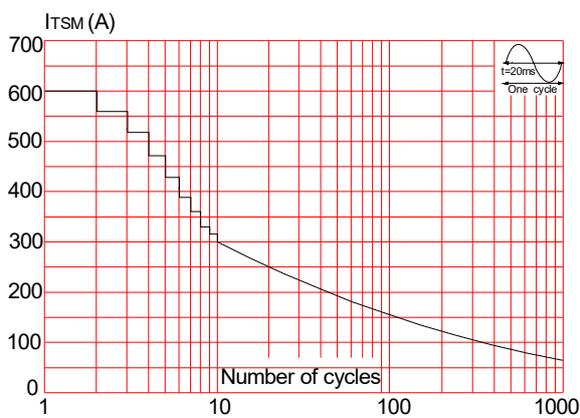


FIG.4: On-state characteristics (maximum values)

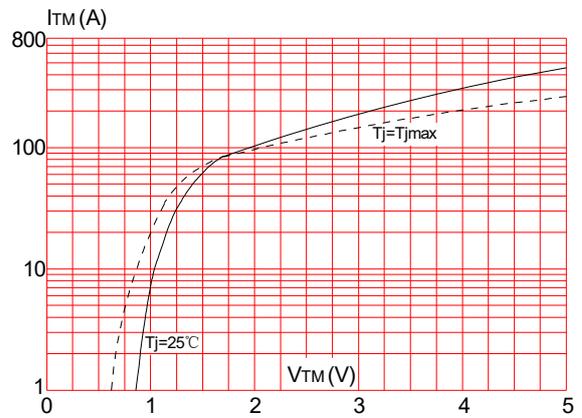


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t ($di/dt < 100\text{A}/\mu\text{s}$)

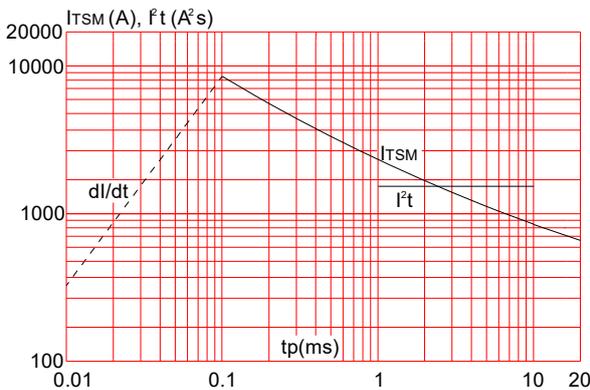


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

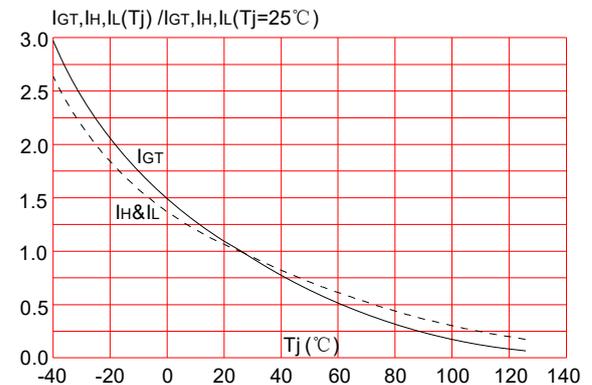
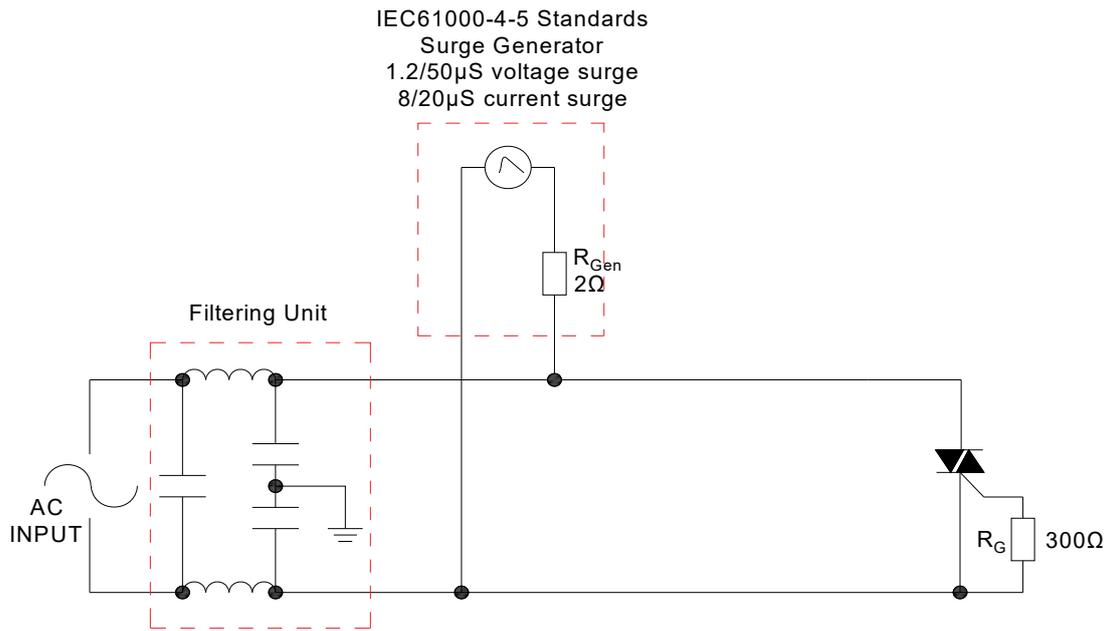


FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



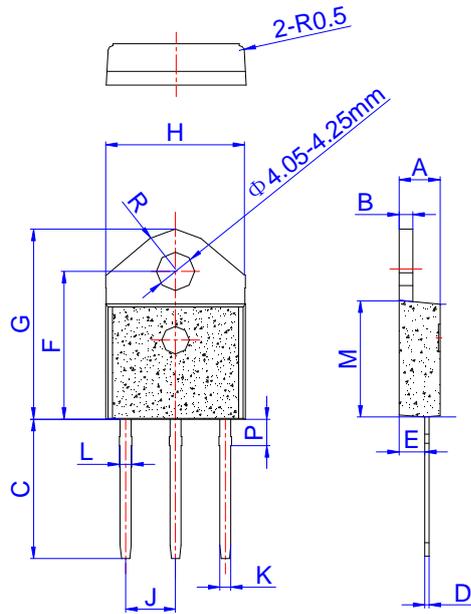
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
JST60Z-1200/1600BW	1200/1600	50	TO-3P(Ins)	30	Tube

Document Revision History

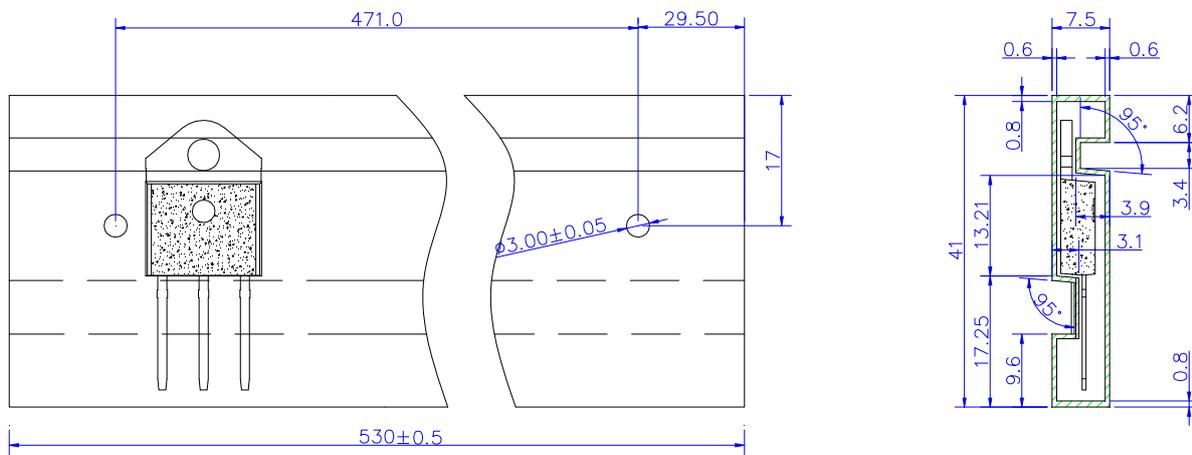
Date	Revision	Changes
Jul 05, 2022	1	Last update

PACKAGE MECHANICAL DATA



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.50		0.70	0.020		0.028
E	2.70		2.90	0.106		0.114
F	15.80		16.50	0.622		0.650
G	20.40		21.10	0.803		0.831
H	15.10		15.50	0.594		0.610
J	5.40		5.65	0.213		0.222
K	1.10		1.40	0.043		0.055
L	1.25		1.45	0.049		0.057
M	12.37		12.77	0.487		0.503
P	2.80		3.00	0.110		0.118
R		4.35			0.171	

DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO-3P	TUBE	30	450	2,250



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